



FEATURES

- No opto feedback
- Patents Pending
- Optimised bipolar output voltages for IGBT/ SiC & Mosfet gate drives
- Configurable dual outputs for all gate drive applications: +15V/-5V, +15V/-10V & +20V/-5V outputs
- Reinforced insulation to UL60950 recognised
- ANSI/AAMI ES60601-1 1M0PP/2M00Ps recognised
- Characterised dv/dt immunity 80kV/us at 1.6kV
- Characterised partial discharge performance
- 5.2kVDC isolation test voltage 'Hi Pot Test'
- Ultra low coupling capacitance 15pF
- DC link voltage 3kVDC
- 5V, 12V & 24V input voltages
- 105°C operating temperature

PRODUCT OVERVIEW

Offering configurable dual output voltages of +15V/-10V, +20V/-5V and +15V/-5V, the MGJ3 series of DC-DC converters is ideal for powering 'high side' and 'low side' gate drive circuits for IGBTs, Silicon and Silicon Carbide Mosfets in bridge circuits. A choice of asymmetric output voltages allows optimum drive levels for best system efficiency and EMI. The MGJ3 series is characterised for high isolation and dv/dt requirements commonly seen in bridge circuits used in motor drives and inverters. A disable/frequency synchronisation pin simplifies EMC filter design. The MGJ3 protection features include short circuit protection and overload protection.



5.2kVDC Isolate	ed 3W Gate Drive S	M DC-DC Converters
	Output 1	Output 2

MGJ3 Series

Order Code ¹	Input Voltage Range	Typical Application	Rated Output Voltage	Rated Output Current	Output Power	Rated Output Voltage	Rated Output Current	Output Power
	V	See page 3	V	mA	W	V	mA	W
MGJ3T05150505MC	4.5 - 9	IGBT	+15	120	1.8	-10	120	1.2
MGJ3T12150505MC	9 - 18	IGBT	+15	120	1.8	-10	120	1.2
MGJ3T24150505MC	18 - 36	IGBT	+15	120	1.8	-10	120	1.2
MGJ3T05150505MC	4.5 - 9	SiC	+20	120	2.4	-5	120	0.6
MGJ3T12150505MC	9 - 18	SiC	+20	120	2.4	-5	120	0.6
MGJ3T24150505MC	18 - 36	SiC	+20	120	2.4	-5	120	0.6
MGJ3T05150505MC	4.5 - 9	MOSFET	+15	150	2.25	-5	150	0.75
MGJ3T12150505MC	9 - 18	MOSFET	+15	150	2.25	-5	150	0.75
MGJ3T24150505MC	18 - 36	MOSFET	+15	150	2.25	-5	150	0.75

SELECTION GUIDE (Continued)										
				Outp	out 1			Outp	out 2	
Order Code ¹	Input Voltage Range	Typical Application	Load Regulation (Typ) ³	Load Regulation (Max) ³	Ripple & Noise (Typ)2	Ripple & Noise (Max) ²	Load Regulation (Typ) ³	Load Regulation (Max) ³	Ripple & Noise (Typ) ²	Ripple & Noise (Max) ²
	V	See page 3	%		mVp-p		%		mVp-p	
MGJ3T05150505MC	4.5 - 9	IGBT	3	10	69	200	3	10	98	150
MGJ3T12150505MC	9 - 18	IGBT	3	10	85	200	3	10	108	150
MGJ3T24150505MC	18 - 36	IGBT	3	10	83	200	3	10	104	150
MGJ3T05150505MC	4.5 - 9	SiC	3	10	118	275	3	10	49	75
MGJ3T12150505MC	9 - 18	SiC	3	10	139	275	3	10	54	75
MGJ3T24150505MC	18 - 36	SiC	3	10	135	275	3	10	52	75
MGJ3T05150505MC	4.5 - 9	MOSFET	3	10	69	200	3	10	49	75
MGJ3T12150505MC	9 - 18	MOSFET	3	10	85	200	3	10	54	75
MGJ3T24150505MC	18 - 36	MOSFET	3	10	83	200	3	10	52	75

1. Components are supplied in tape and reel packaging, please refer to package specification section. Orderable part numbers are MGJ3TXX150505MC-R7 (23 pieces per reel), or MGJ3TXX150505MC-R13 (92 pieces per reel).

See ripple & noise test method.
Between 75% and 100% rated output current.

SELECTION GUIDE

All specifications typical at T_A=25°C, nominal input voltage and rated output current unless otherwise specified.

MGJ3 Series

5.2kVDC Isolated 3W Gate Drive SM DC-DC Converters

SELECTION GUIDE (Continued)										
	and the second se	ent oad	ĥ	Ń	loitance		MTTF ¹				
Order Code	Nom V v at Rr		Efficiency (Min) Efficiency (Typ)		내 Isolation Capacitance	MIL 217		Telecordia			
	V	mA		<i>//</i>			kHrs				
MGJ3T05150505MC	5	760	75	78.5	15	889		6662			
MGJ3T12150505MC	12	310	78	82	15	939		6596			
MGJ3T24150505MC	24	155	77	81	15	915		659	6		
INPUT CHARACTER	ISTICS										
Parameter			ditions			Min.	Тур.	Max.	Units		
			nput types			4.5	5	9			
Voltage range			input types			9	12	18	V		
			input types			18	24	36			
			on threshold MGJ3T05				4.1				
			off threshold MGJ3T05 on threshold MGJ3T12	-			3.0 8.1				
Under voltage lock out			off threshold MGJ3T12				8.1 7.5		V		
			on threshold MGJ3T12	-			16.7				
				16.1							
			off threshold MGJ3T24 nput types	r							
Input ripple current			input types					mA			
input inpple current			input types				12 9		p-p		
OUTPUT CHARACTE	RISTICS										
Parameter		Con	ditions			Min.	Тур.	Max.	Units		
Minimum load		Belo	w 10% load, 5V and 15	V outputs are clamped	to 6V and 16V respective	ely 10			%		
Voltage set point accura	су	Non	inal output voltages are	e at 75% loading			±4		%		
Line regulation		Low	line to high line					2	%		
T		Pea	c deviation (50-100% &	100-50% load swing)			1.2		%Vout		
Transient response		Sett	ling time				0.25		ms		
ISOLATION CHARAC	TERISTICS										
Parameter		Con	ditions			Min.	Тур.	Max.	Units		
Isolation test voltage		Flas	h tested for 1 second			5200			VDC		
-			ification tested for 1 mi	nute		5200					
Declahaman		Viso	= 1kVDC			100		0000	GΩ		
Resistance	a ta sa di sa tha sa s	A Laure	$\mathbf{x} = \mathbf{f} + \mathbf{h} + $					3000	V		
Continuous barrier with	Ŭ	Non	-safety barrier application	on							
Continuous barrier with GENERAL CHARACT	Ŭ		·	DN			-				
Continuous barrier with GENERAL CHARACT Parameter	Ŭ		-safety barrier application	on		Min.	Typ.	Max.			
Continuous barrier with GENERAL CHARACT Parameter Switching frequency	TERISTICS		·	on 		Min.	Тур. 100	Max.			
Continuous barrier with GENERAL CHARACT Parameter Switching frequency TEMPERATURE CHA	TERISTICS	Con	ditions				100		kHz		
Continuous barrier with GENERAL CHARACT Parameter Switching frequency TEMPERATURE CHA Parameter	TERISTICS	Con	ditions	DN		Min.		Max.	kHz		
Continuous barrier with GENERAL CHARACT Parameter Switching frequency TEMPERATURE CHA	TERISTICS	Con	ditions	DN			100		kHz		
Continuous barrier with GENERAL CHARACT Parameter Switching frequency TEMPERATURE CHA Parameter Operation Storage	TERISTICS	Con Con See	ditions			Min. -40	100	Max. 105	kHz Units		
Continuous barrier with GENERAL CHARACT Parameter Switching frequency TEMPERATURE CHA Parameter Operation Storage Product temperature ris ABSOLUTE MAXIMU	TERISTICS ARACTERISTICS se above ambient JM RATINGS	Con Con See	ditions ditions derating graphs			Min. -40 -50	100 Typ. 18	Max. 105	kHz Units		
Continuous barrier with GENERAL CHARACT Parameter Switching frequency TEMPERATURE CHA Parameter Operation Storage Product temperature ris ABSOLUTE MAXIMU Short-circuit protection	TERISTICS ARACTERISTICS se above ambient JM RATINGS	Con Con See	ditions ditions derating graphs			Min. -40 -50 Continue	100 Typ. 18	Max. 105	kHz Units		
Continuous barrier with GENERAL CHARACT Parameter Switching frequency TEMPERATURE CHA Parameter Operation Storage Product temperature ris	TERISTICS ARACTERISTICS se above ambient JM RATINGS	Con Con See	ditions ditions derating graphs			Min. -40 -50	100 Typ. 18	Max. 105	Units		

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MGJ3 Series

5.2kVDC Isolated 3W Gate Drive SM DC-DC Converters

TECHNICAL NOTES

ISOLATION VOLTAGE

'Hi Pot Test', 'Flash Tested', 'Withstand Voltage', 'Proof Voltage', 'Dielectric Withstand Voltage' & 'Isolation Test Voltage' are all terms that relate to the same thing, a test voltage, applied for a specified time, across a component designed to provide electrical isolation, to verify the integrity of that isolation.

Murata Power Solutions MGJ3 series of DC-DC converters are all 100% production tested at 5.2kVDC for 1 second and qualification tested at 5.2kVDC for 1 minute. A question commonly asked is, "What is the continuous voltage that can be applied across the part in normal operation?"

When the insulation in the MGJ3 series is not used as a safety barrier , i.e. provides functional isolation only, continuous or switched voltages across the barrier up to 3kV are sustainable. Long term reliability testing at these voltages continues. Peak Inception voltages measured were in excess of 3.5kV when testing for partial discharge in accordance with IEC 60270. Please contact Murata for further information.

The MGJ3 series has been recognised by Underwriters Laboratory to 250 Vrms Reinforced Insulation, please see safety approval section below.

REPEATED HIGH-VOLTAGE ISOLATION TESTING

It is well known that repeated high-voltage isolation testing of a barrier component can actually degrade isolation capability, to a lesser or greater degree depending on materials, construction and environment. We therefore strongly advise against repeated high voltage isolation testing, but if it is absolutely required, that the voltage be reduced by 20% from specified test voltage.

SAFETY APPROVAL

ANSI/AAMI ES60601-1

The MGJ3 series is recognised to ANSI/AAMI ES60601-1 and provides 1 MOPP (Means Of Patient Protection) and 2 MOOP (Means Of Operator Protection) based upon a working voltage of 250 Vrms max, between Primary and Secondary.

UL 60950

The MGJ3 series has been recognised by Underwriters Laboratory (UL) to UL 60950 for reinforced insulation to a working voltage of 250Vrms with a maximum measured product operating temperature of 105°C.

Creepage and clearance 7mm.

FUSING

The MGJ3 Series of converters are not internally fused so to meet the requirements of UL an anti-surge input line fuse should always be used with ratings as defined below. Input Voltage, 5V 2A Input Voltage, 12V 1A

Input Voltage, 24V 0.5A All fuses should be UL recognised, 125V rated.

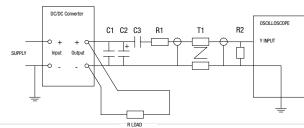
CHARACTERISATION TEST METHODS

Ripple & Noise Characterisation Method

Ripple and noise measurements are performed with the following test configuration.

C1	1 µF X7R multilayer ceramic capacitor, voltage rating to be a minimum of 3 times the output voltage of the DC-DC converter
C2	10μ F tantalum capacitor, voltage rating to be a minimum of 1.5 times the output voltage of the DC-DC converter with an ESR of less than $100m\Omega$ at 100 kHz
C3	100nF multilayer ceramic capacitor, general purpose
R1	450Ω resistor, carbon film, ±1% tolerance
R2	50Ω BNC termination
T1	3T of the coax cable through a ferrite toroid
RLOAD	Resistive load to the maximum power rating of the DC-DC converter. Connections should be made via twisted wires

Differential Mode Noise Test Schematic



MGJ3 Series

5.2kVDC Isolated 3W Gate Drive SM DC-DC Converters

APPLICATION NOTES

Start-up times

Typical start up times for this series, with no additional output capacitance are:

Part No.	Start-up times
Fait NU.	ms
MGJ3T05150505MC	15
MGJ3T12150505MC	15
MGJ3T24150505MC	15

Disable/Frequency synchronisation

Please refer to application notes for further information.

		Min	Тур	Max	Units
	Pull Down Current		0.5		mA
Disable/Sync ¹	Input High	2		5	V
	Input Low	0			V
Synchronisation	Frequency Range	90	100	110	kHz
Synchionisation	Duty Cycle	25		75	%

The Disable/Synchronization pin has three modes:

1. When a DC logic low voltage is applied to this pin the MGJ3 is disabled and enters a low quiescent current sleep mode.

2. When this pin is left floating or a DC logic high (CMOS/TTL compatible) voltage is applied the MGJ3 is enabled and operates at the programmed frequency of 100kHz. 3. When a square wave of between 90kHz and 110kHz is applied to this pin, the switcher operates at the same frequency as the square wave. The falling edge of the square wave corresponds to the start of the switching cycle. If the signal is slower than 25Hz, it will be interpreted as enabling and disabling the part. If the MGJ3 is disabled, it must be disabled for 7 clock cycles before being re-enabled.

Note: The DIS/Sync pin is a high impedance TTL input and can be triggered by noise from external circuits if not treated carefully. It is advised that any pcb traces connected to the DIS/Sync pin are kept as short as possible and away from other noisy pcb traces. The track should follow a similar route to the return path to avoid differential noise pick up. If the pin is not used for synchronisation then a 22nF capacitor can be added from DIS/Sync pin to –Vin to suppress noise.

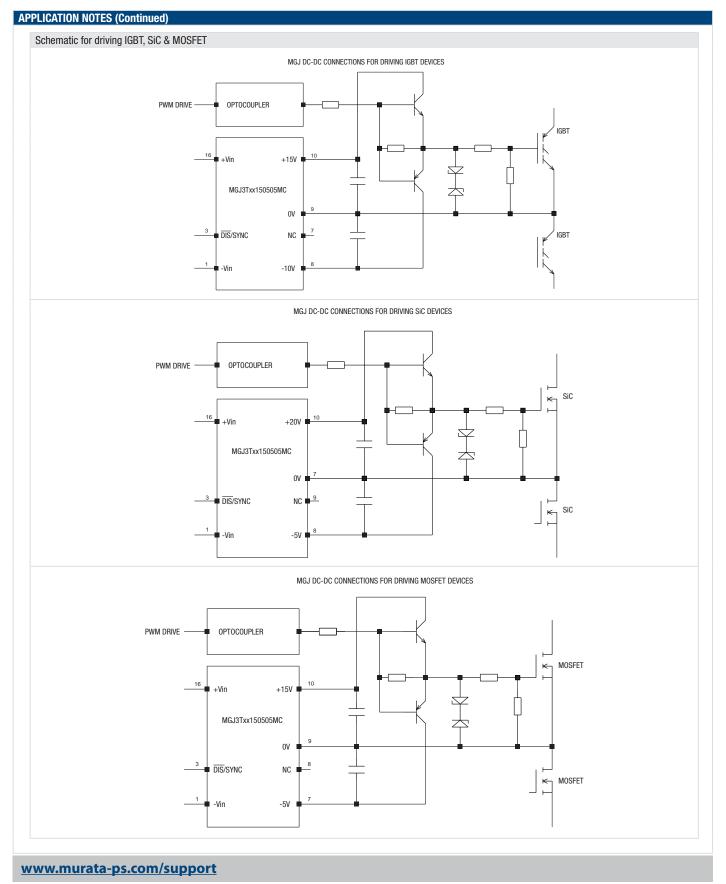
Output configurations for power switches

Terminal	IGBT	SIC	MOSFET
(P10) 15V Output	+15V 0.12A	+20V 0.12A	+15V 0.15A
(P9) 15V Return 5VA Output	OV	No connection	OV
(P7) 5VA Return 5VB Output	No connection	OV	-5V 0.15A
(P8) 5VB Return	-10V 0.12A	-5V 0.12A	No connection

Output Voltage	Maximum output capacitance
V	μF
15	120
5	220

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MGJ3 Series

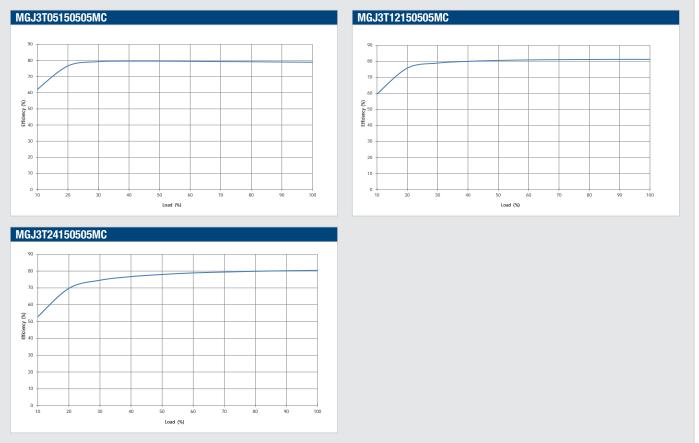
5.2kVDC Isolated 3W Gate Drive SM DC-DC Converters

Rohs Compliance, MSL AND PSL INFORMATION



This series is compatible with RoHS soldering systems with a peak reflow solder temperature of 245°C and Time Above Liquidus for 90 seconds. as per J-STD-020D.1. The pin termination finish on this product series is Gold with Nickel Pre-plate. The series is backward compatible with Sn/Pb soldering systems. The series has a Moisture Sensitivity Level (MSL) 1. Samples of the product series were tested in accordance with the conditioning described for MSL level 1 in IPS/J-STD-020D.1. The product series passed electrical tests, co-planarity and visual inspection criteria.

EFFICIENCY VS LOAD

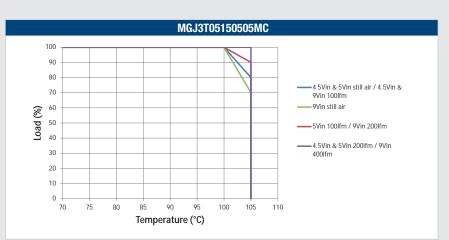


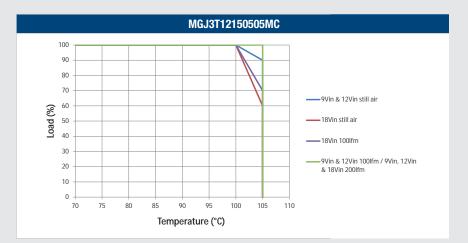
MGJ3 Series

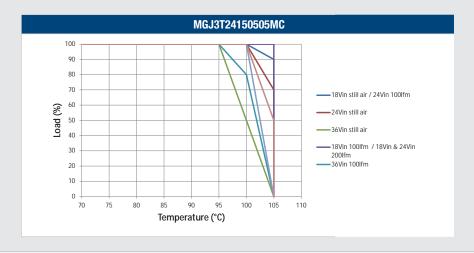
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DERATING GRAPHS

Derating curves are based on IPC-9592. With no derating some components may be operating at the manufacturers maximum temperature ratings.







MGJ3 Series

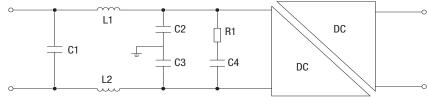
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EMC FILTERING AND SPECTRA

FILTERING

C4

The following filter circuit and filter table shows the input filters typically required to meet EN55022 Quasi-Peak Curve A or B. If a high dv/dt above 80kV/us is expected from output to input it is advised that a common mode filter is used on the input without Y capacitors. This will reduce the common mode current and reduce interference with primary side circuits.

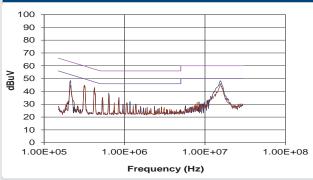


C1, C2 & C3 Polyester or ceramic capacitor

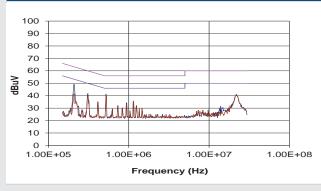
Electrolytic capacitor (note R1 could be omitted if C4 has ESR >= R1)

TO MEET CURVE B							
Part Number	C1	L1	L2	C2	C3	R1	C4
MGJ3T05150505MC	1.5µF	476R8SC		10nF	10nF	500m Ω	220µF
MGJ3T12150505MC	1.5µF	476R8SC		10nF	10nF	500m Ω	220µF
MGJ3T24150505MC	1.5µF	476R8SC		10nF	10nF	500m Ω	220µF

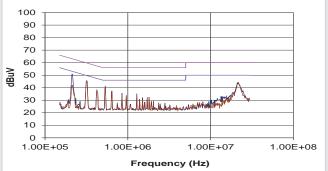
MGJ3T05150505MC



MGJ3T24150505MC

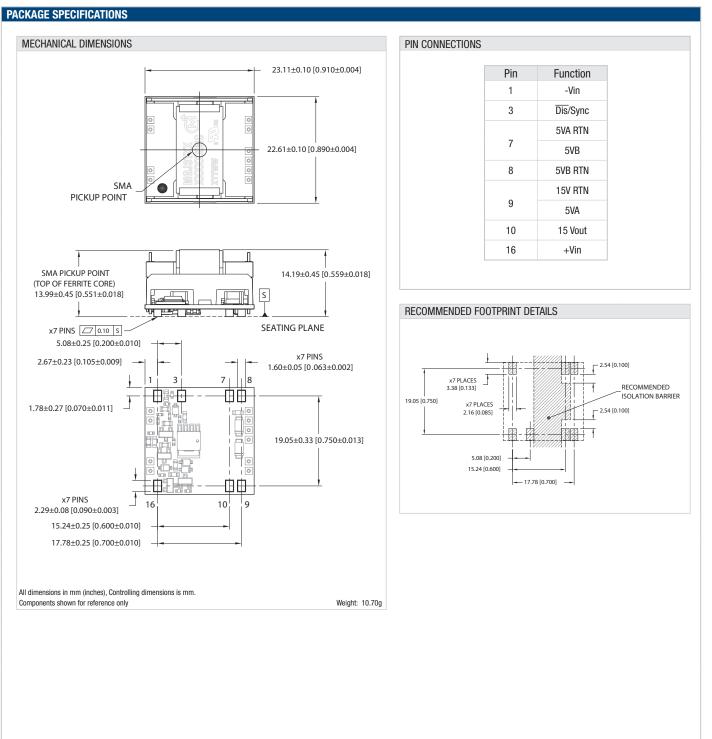


MGJ3T12150505MC



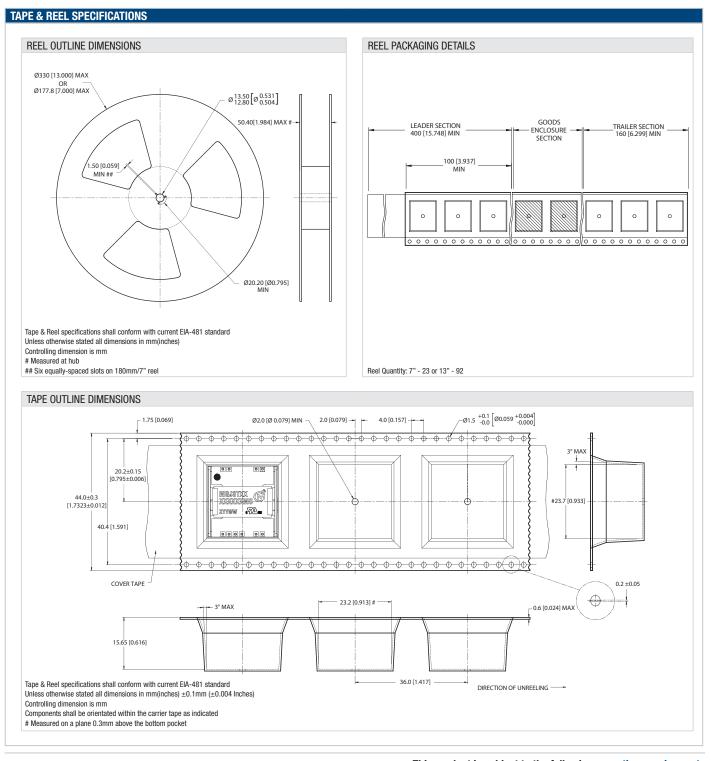
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MGJ3 Series

5.2kVDC Isolated 3W Gate Drive SM DC-DC Converters



This product is subject to the following <u>operating requirements</u> and the <u>Life and Safety Critical Application Sales Policy</u>: Refer to: <u>http://www.murata-ps.com/requirements/</u>

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<u>MGJ3T24150505MC-R13</u> <u>MGJ3T12150505MC-R13</u> <u>MGJ3T05150505MC-R13</u> <u>MGJ3T12150505MC-R7</u> MGJ3T24150505MC-R7 MGJ3T05150505MC-R7